Characteristics BAL-CW1250D3

1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter	Value			Unit
	Farameter		Тур	Max	Oilit
P _{IN}	Average power RF _{IN}			24	dBm
	ESD ratings MIL STD883C (HBM: C = 100 pF, R = 1.5 k Ω , air discharge)	2000			
V _{ESD}	ESD ratings charged device model (JESD22-C101-D)	500			V
	ESD ratings machine model (MM: C = 200 pF, R = 25 Ω , L = 500 nH)	200			
T _{OP}	Operating temperature	-30 to +85		°C	

Table 2. Impedances ($T_{amb} = 25$ °C)

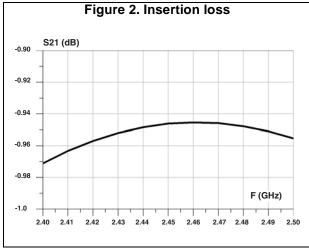
Symbol	Parameter -		Value			
Symbol			Тур	Max Unit		
Z _{OUT}	Nominal differential output impedance		matched		Ω	
Z _{IN}	Nominal input impedance		50		Ω	

Table 3. RF performance ($T_{amb} = 25 \text{ °C}$)

Symbol	Parameter	Value			Unit
		Min	Тур	Max	Oill
F	Frequency range (bandwidth)	2400		2500	MHz
IL	Insertion loss in bandwidth		0.97		dB
RL _{SE}	Single ended return loss in bandwidth		-21		dB
RL _{DIFF}	Differential return loss in bandwidth		-24		dB
фimb	Phase imbalance	-10		10	0
Aimb	Amplitude imbalance	-1	0.1	1	dB
Att _{2f0}	2nd harmonic attenuation		-19		dB

BAL-CW1250D3 Characteristics

1.1 Measurements



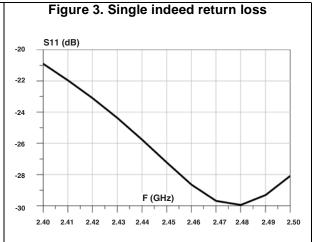


Figure 4. Differential return loss

S22 (dB)

-24

-28

-30

-32

-34

-36

-38

-40

2.40 2.41 2.42 2.43 2.44 2.45 2.46 2.47 2.48 2.49 2.50

Figure 5. Amplitude imbalance

Absolute Aimb (dB)

-0.36

-0.35

-0.34

-0.33

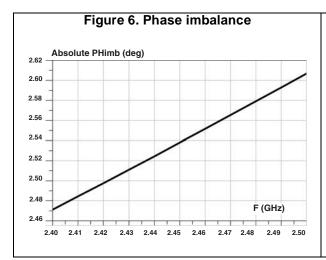
-0.32

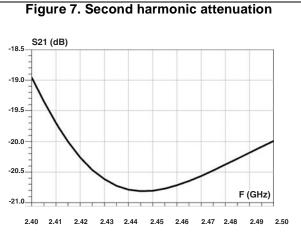
-0.31

-0.30

-0.29

2.40 2.41 2.42 2.43 2.44 2.45 2.46 2.47 2.48 2.49 2.50





2 Package information

- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

2.1 Flip-Chip package information

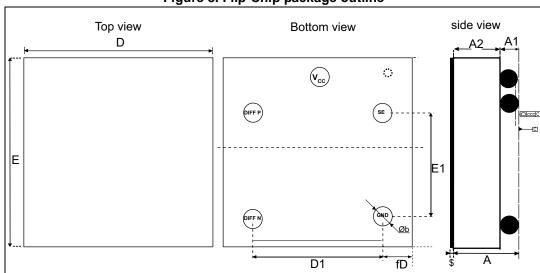


Figure 8. Flip-Chip package outline

Table 4. Flip-Chip package mechanical data

Parameter	Description	Min.	Тур.	Max.	Unit
Α	Bump height + substrate thickness	0.570	0.630	0.690	mm
A1	Bump height	0.155	0.205	0.255	mm
A2	Substrate thickness		0.400		mm
b	Bump diameter	0.215	0.255	0.295	mm
D	Y dimension of the die	1.150	1.200	1.250	mm
D1	Y pitch		0.760		mm
Е	X dimension of the die	0.940	0.990	1.040	mm
E1	X pitch		0.400		mm
fD	Distance from bump to edge of die on Y axis		0.105		mm
ccc				0.05	mm
\$			0.025		mm

BAL-CW1250D3 Package information

Figure 9. Footprint

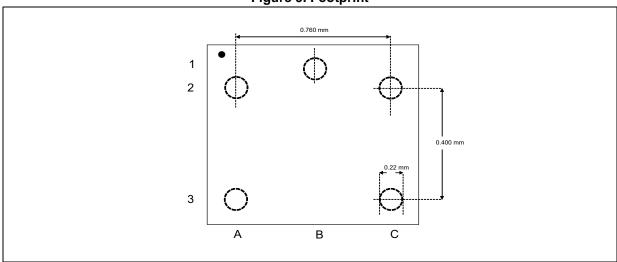
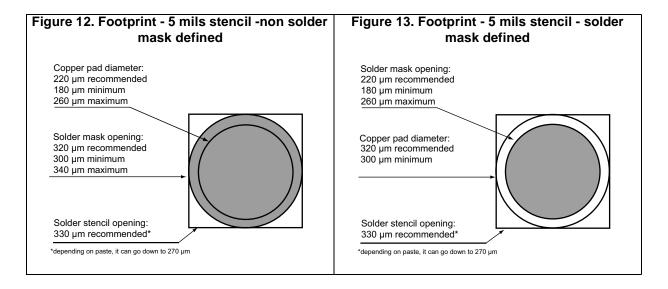


Figure 10. Footprint - 3 mils stencil -non solder Figure 11. Footprint - 3 mils stencil - solder mask defined mask defined Copper pad diameter: Solder mask opening: 220 µm recommended 220 µm recommended 180 µm minimum $180~\mu m$ minimum 260 µm maximum 260 µm maximum Copper pad diameter: 320 µm recommended Solder mask opening: 320 µm recommended 300 µm minimum $300~\mu m$ minimum 340 µm maximum Solder stencil opening: Solder stencil opening: 220 µm recommended 220 μm recommended



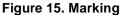
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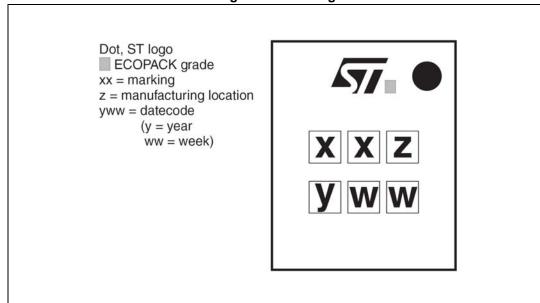
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Package information BAL-CW1250D3

Figure 14. Recommended land pattern (used for balun characterization)





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BAL-CW1250D3 Package information

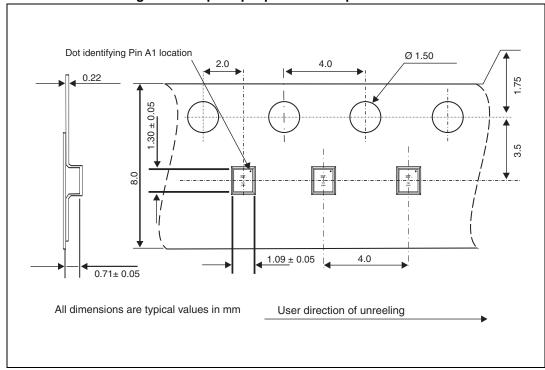


Figure 16. Flip-Chip tape and reel specifications

Note: More information is available in the STMicroelectronics Application note: AN2348 Flip-Chip: "Package description and recommendations for use"

Application information 3

2.4G/5G RF transceiver BAL-CW1250D3 2.4GHz FEM BPF 2.4GHz DIP2450-01D3 Rx/Tx BPF50-01D3 5GHz FEM

Figure 17. Application schematic

Note:

More information is available in the application notes:

AN2348 Flip-Chip package description and recommendations for use

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4 Ordering information

Table 5. Ordering information

Part Number	Marking	Package	Weight	Base Qty	Delivery Mode
BAL-CW1250D3	SG	Flip-Chip	1.46 mg	5000	Tape and reel(7")

5 Revision history

Table 6. Document revision history

Date	Revision	Changes
23-May-2013	1	Initial release.
23-Sep-2015	2	Updated Figure 8. Added Figure 10, Figure 11, Figure 12, Figure 13 and Table 4. Reformatted to current standards.



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